Low frequency transistor (for amplification)

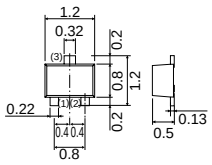
2SD2696

●Structure
NPN Silicon Epitaxial Planar Transistor

●Features
1) The transistor of 400mA class which went only with 2012 size conventionally is attained in 1208 size.
2) Collector saturation voltage is low.
   $V_{CE\,(sat)}$: max. 300mA at I_C = 100mA / I_B = 2mA

●External dimensions (Unit : mm)

VMT3



(1) Base
(2) Emitter
(3) Collector

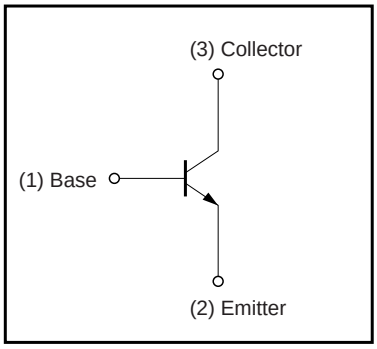
Abbreviated symbol : UH

●Applications
Switching

●Packaging specifications

Type	Package	Taping
	Code	T2L
	Basic ordering unit (pieces)	8000
2SD2696		○

●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	30	V
Collector-emitter voltage	V_{CEO}	30	V
Emitter-base voltage	V_{EBO}	6	V
Collector current	I_C	400	mA
	I_{CP} *1	800	mA
Power dissipation	P_D *2	150	mW / TOTAL
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	−55 to +150	°C

*1 Pw=10ms, Single pulse
*2 Each terminal mounted on a recommended land.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV_{CEO}	30	–	–	V	I_C=1mA
Collector-base breakdown voltage	BV_{CBO}	30	–	–	V	I_C=10μA
Emitter-base breakdown voltage	BV_{EBO}	6	–	–	V	I_E=10μA
Collector cut-off current	I_{CBO}	–	–	100	nA	V_{CB}= 30V
Emitter cut-off current	I_{EBO}	–	–	100	nA	V_{EB}= 6V
Collector-emitter saturation voltage	$V_{CE\,(sat)}$	–	120	300	mV	I_C=100mA, I_B= 2mA
DC current gain	h_{FE}	270	–	680	–	V_{CE}=2V, I_C=100mA
Transition frequency	f_T	–	400	–	MHz	V_{CE}=2V, I_E= −100mA, f=100MHz
Output capacitance	C_{ob}	–	3.0	–	pF	V_{CB}=10V, I_E= 0A, f=1MHz

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).
Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.
In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.